Bis(2-oxoindolin-3-ylidene)-benzodifuran-dione-based D–A polymers for high-performance n-channel transistors†

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Conjugated polymers based on a bis(2-oxoindolin-3-ylidene)-benzodifuran-dione (BIBDF) unit displayed promising performances for their application in organic thin-film transistors (OTFTs). Herein, three new BIBDF-based donor–acceptor (D–A) polymers, containing thieno[3,2-b]thiophene (TT), (E)-2-(2-(thiophen-2-yl)vinyl)thiophene (TVT) and (2-(thiophene-2-yl)alkynyl)thiophene (TAT) as donors, were synthesized and characterized. The results indicated that the donor unit plays important roles in affecting the absorption bands, HOMO levels, lamellar packing and π–π stacking distances of the BIBDF-based polymers. The OTFT devices based on the three polymers were fabricated, and their field-effect performance and environmental stability were also characterized. All three BIBDF based polymers showed good n-type field-effect characteristics. The PBIBDF-TT showed the highest electron mobility of 0.65 cm² V⁻¹ s⁻¹ and the best environmental stability, while the PBIBDF-TAT showed the lowest electron mobility of 0.13 cm² V⁻¹ s⁻¹. The corresponding crystalline structures and morphologies revealed that the PBIBDF-TT and PBIBDF-TVAT showed close π–π distances and long-range ordered, lamellar crystalline structures both of which contributed to the high charge carrier mobility. The PBIBDF-TAT with close π–π distances but poor crystalline structures showed miserable performance. Overall, this work showed the correlation of the microstructures and properties of BIBDF-based polymers, and the field-effect performances can be effectively optimized by introducing different donor units.

1. Introduction

Solution-processable conjugated polymers have attracted considerable attention due to their application in low-cost, lightweight and flexible organic thin-film transistors (OTFTs). Among conjugated polymers, donor–acceptor (D–A) polymers have been extensively studied because their molecular designs allow one to tailor their electronic structures, including the photon absorption, highest occupied molecular orbital (HOMO) energy levels, lowest unoccupied molecular orbital (LUMO) energy levels and energy bandgaps. Benefiting from the development of new D–A conjugated polymers, as well as optimized processing and device fabrication, great progress has been made in developing high-performance polymer semiconductors. Excellent hole transporting polymer semiconductors with mobility comparable to small molecules have been developed in the past few years. However, the overall development of n-channel polymers still lags behind their p-channel counterparts in terms of amount, mobility, and so on. To design and synthesize an n-channel polymer, the LUMO energy level is the key factor and must be lower than or close to −4.0 eV for stable electron transport. For a D–A conjugated polymer, the incorporation of a strong electron-deficient acceptor unit into a D–A polymer can usually give rise to a low-lying LUMO (high electron affinity) level which has been confirmed to be beneficial for the stability of charge transport. Therefore an important approach in developing n-channel polymer semiconductors is the synthesis of a D–A polymer, which by virtue of its modular nature can facilitate the tuning of the LUMO energy level (−4.0 eV) depending on the choice of the strong electron-accepting unit.

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So far, the D–A polymers found to be typical n-channel semiconductors for developing high-performance OTFTs have only focused on those containing lactam- or imide-based acceptor units such as diketopyrrolopyrrole (DPP), naphthalene diimide (NDI) and perylene diimide (PDI). Recently, a new electron-deficient fused aromatic ring bis(2-oxoindolin-3-ylidine)-benzodifuran-dione (BIBDF) and its polymers have been developed by us and other groups. BIBDF has a large fused aromatic ring with symmetric and planar structure, which should increase the π–π overlap and intramolecular interaction. The two lactone groups in the central core coupled with the two lactam groups make the BIBDF unit strongly electron deficient.

Indeed, the reported polymers based on a BIBDF unit exhibited n-type or ambipolar transport characteristics with remarkably high mobilities approaching 1 cm² V⁻¹ s⁻¹. Although a few polymers based on BIBDF have been reported and high electron mobilities have been achieved, the BIBDF based n-type materials are still worth further investigation considering their promising performances.

In this paper, we presented the synthesis of three new D–A polymers (Scheme 1) based on a BIBDF unit and different electron-donors (thieno[3,2-b]thiophene (TT), (E)-2-[2-(thiophen-2-yl)vinyl]thiophene (TVT) and (2-[thiophene-2-yl]alkynyl)thiophene (TAT)), and the characterization of their thermal, optical, electrochemical, microstructural, and OTFT properties. The results indicated that the BIBDF-based polymers showed varied absorption bands and molecular energy levels and also different micro-structures in solid films; thus, three polymers display varied field-effect performances in OTFT devices. This work has showed the correlation of the microstructures and properties of BIBDF-based polymers, and the field-effect performances can be effectively optimized by introducing different donor units.

2. Results and discussion

2.1. Synthesis and characterization

The synthetic routes of the relevant monomers and polymers are illustrated in Scheme 1. The compound benzo[1,2-b:4,5-b’]-difuran-2,6(3H,7H)-dione (1) was conveniently synthesized from the dehydration reaction of 2,5-dihydroxy-1,4-benzenedi-acetic acid. 6-Bromoinodioline-2,3-dione was N-alkylated with a 4-bromo-alkyl group to form 6-bromo-1-(4-octadecyldocosyl)-indoline-2,3-dione (2), which was easily converted to the dibromo-monomer BIBDF by reacting with compound 1 in acetic acid at about reflux temperature. In order to obtain good solubility for the final BIBDF-based polymer, two long branched 4-octadeyldocosyl chains were introduced into a BIBDF unit. Finally, three polymers were synthesized by Stille cross-coupling polymerizations with a 1 : 1 monomer ratio in the presence of tris(dibenzylidene-acetone)dipalladium- (Pd₂(dba)₃) as a catalyst and tri(o-tolyl)phosphine (P(o-tol)₃) as a ligand to give a black solid. PBIBDF-TT and PBIBDF-TV displayed good solubility in solvents such as tetrahydrofuran, chloroform and chlorobenzene at room temperature. PBIBDF-TAT was only soluble in hot chloroform and hot chloride-containing solvents. Polymers were verified by elemental analysis. The number-average molecular weights (Mn) and polydispersity index (PDI) of the polymers were determined by gel-permeation chromatography (GPC) with trichlorobenzene as an eluent. The GPC plots are shown in Fig. S1 (ESI) and the
corresponding data are also listed in Table S1.† The number-average molecular weights were 26.47 kDa (PDI = 1.65) for PBIBDF-TT, 28.07 kDa (PDI = 1.72) for PBIBDF-TV, and 23.95 kDa (PDI = 1.83) for PBIBDF-TAT.

The thermogravimetric analysis (TGA) and differential scanning calorimetry (DSC) curves of the three BIBDF-based polymers are shown in Fig. 1 and the decomposition temperatures (Td) are collected in Table S1.† The temperatures of 5% weight-loss were chosen as the onset point of decomposition, which were thermally stable up to temperatures of 375–389 °C. The thermal-stability of the three polymers was adequate for application in optoelectronic devices. DSC curves clearly showed endothermic peaks at 22–24 °C during heating up, and corresponding exothermic peaks at 19–20 °C were also observed when they were cooled down. The same transition temperatures of the three polymers should be attributed to the phase transition temperature caused by the melting of the long alkyl chains.8

2.2. Optical properties

The normalized UV-vis-NIR absorption spectra of these three BIBDF-based polymers in dilute chloroform solutions and as thin films casted from chloroform are shown in Fig. 2. Polymers displayed typical dual-bands consisting of sharp ones at the high energy region and more intense, broader ones with additional shoulder peaks at the low energy region. As listed in Table 1, the absorption maxima (λmax) of PBIBDF-TT, PBIBDF-TV and PBIBDF-TAT in a chloroform solution were located at 827, 835 and 780 nm, respectively. From the solution state to a solid film, the λmax of the three polymers showed small red-shifts of about 8–11 nm. The absence of strong red-shifts from solution to film could be ascribed to the probable pre-aggregation in solution.9 The absorption of PBIBDF-TAT was blue-shifted compared with those of PBIBDF-TT and PBIBDF-TV; this is because the triple bond is electron-withdrawing and indicates that the triple bond as a linker results in a weaker donor compared to the single bond/double bond as a linker.10 The edges of the film absorption bands for PBIBDF-TT, PBIBDF-TV and PBIBDF-TAT were at 968, 1015, and 906 nm, respectively. The corresponding optical bandgaps of PBIBDF-TT, PBIBDF-TV and PBIBDF-TAT were 1.28, 1.22, and 1.37 eV, respectively. The narrow bandgaps were due to the extended π-conjugation along the polymer backbone as well as strong intramolecular and intermolecular interactions.8b

2.3. Electrochemical properties

The LUMO and HOMO energy levels of polymers, which are closely related to the transport characteristics of OTFTs, can be
determined by cyclic voltammetry (CV). The cyclic voltammograms of the three polymers as thin films are shown in Fig. 3a. The electrochemical data are summarized in Table 1 and are schematically depicted in Fig. 3b. The potentials were referenced to Ag/Ag⁺ and the redox Fc/Fc⁺ was assumed at an absolute energy level of 4.8 eV to vacuum. The redox Fc/Fc⁺ was measured under the same conditions as polymer thin-films and was located at 0.05 V related to the Ag/Ag⁺ electrode. As listed in Table 1, the oxidation onset potentials (E_{ox}^{onset}) of PBIBDF-TT, PBIBDF-TVT, and PBIBDF-TAT were 0.82, 0.68, and 0.85 V, corresponding to the HOMO energy levels of −5.57, −5.43, and −5.60 eV, respectively. PBIBDF-TVT had a slightly higher HOMO energy level than those of the other two polymers because of the existence of the relatively strong donating \(-\)2-(2-(thiophen-2-yl)vinyl)thiophene. The onset reduction potentials (E_{red}^{onset}) of PBIBDF-TT, PBIBDF-TVT, and PBIBDF-TAT were located at −0.65, −0.64, and −0.66 V. The three polymers had almost the same E_{red}^{onset} and correspondingly showed similar LUMO energy levels of −4.10, −4.09, and −4.11 eV, because typically the LUMO energy levels were controlled by the LUMO level of the acceptor unit.\(^{11}\) The electrochemical bandgaps estimated from the difference between the HOMO and LUMO energy levels of BIBDF-based polymers, the three polymers should be suitable candidates as n-channel semiconductors for the injection, accumulation, and transport of electrons when an appropriate single metal (such as Au) is used.

### 2.4. OTFT Performance

Bottom-gate/top-contact transistors were fabricated based on the polymers as semiconductor layers. The evaluation of OTFTs was carried out under vacuum (3 × 10⁻⁴ mbar). First, polymer thin-films were prepared on a conventional octadecyltrichlorosilane (OTS)-modified SiO₂/Si substrate by spin coating. As shown in Fig. S2, the three polymers displayed clear n-channel transport characteristics and their electrical properties are summarized in Table 2. It is well known that fluoropolymer Cytop surfaces were most suitable for upper-deposited semiconductors, especially for Cytop-modified surfaces which are themselves hydroxyl-group-free and hydrophobic.\(^{7,13}\) Therefore, we also fabricated OTFTs based on the polymers on Cytop-modified SiO₂/Si substrates. The mobilities of the non-annealed (N/A) devices of PBIBDF-TT, PBIBDF-TVT, and PBIBDF-TAT were 0.18, 0.18, and 0.04 cm² V⁻¹ s⁻¹ (Fig. S3†), respectively. As far as the n-type solution processable semiconductors, annealing of the polymer films generally provides an excellent approach for achieving an ordered film. The thermal-annealing can improve the crystallinity of the films while significantly

### Table 1  Optical and electrochemical properties of the three BIBDF-based polymers

<table>
<thead>
<tr>
<th>Polymer</th>
<th>(\lambda_{\text{abs max}}) (nm)</th>
<th>(\lambda_{\text{abs onset}}) (nm)</th>
<th>(E_{\text{opt g}}^{a}) (eV)</th>
<th>HOMO(^{b}) (eV)</th>
<th>LUMO(^{b}) (eV)</th>
<th>(E_{\text{ec g}}^{c}) (eV)</th>
</tr>
</thead>
<tbody>
<tr>
<td>PBIBDF-TT</td>
<td>827</td>
<td>838</td>
<td>1.28</td>
<td>−5.57</td>
<td>−4.10</td>
<td>1.47</td>
</tr>
<tr>
<td>PBIBDF-TVT</td>
<td>835</td>
<td>844</td>
<td>1.22</td>
<td>−5.43</td>
<td>−4.09</td>
<td>1.34</td>
</tr>
<tr>
<td>PBIBDF-TAT</td>
<td>716 (780)</td>
<td>788</td>
<td>1.37</td>
<td>−5.60</td>
<td>−4.11</td>
<td>1.49</td>
</tr>
</tbody>
</table>

\(^{a}\) \(E_{\text{opt g}} = 1240/\lambda_{\text{abs onset}}\) (in film).
\(^{b}\) HOMO = −(4.75 + E_{\text{ox}^{onset}}), LUMO = −(4.75 + E_{\text{red}^{onset}}).
\(^{c}\) \(E_{\text{ec g}} = \{\text{HOMO}–\text{LUMO}\}\).
Table 2 OTFT performances of the three BIBDF-based polymers

<table>
<thead>
<tr>
<th>Dielectric layer</th>
<th>Annealing temperature [°C]</th>
<th>μ_{e,max} (cm² V⁻¹ s⁻¹)</th>
<th>μ_{e,avg} (cm² V⁻¹ s⁻¹)</th>
<th>I_{on}/I_{off}</th>
<th>V_{th} (V)</th>
</tr>
</thead>
<tbody>
<tr>
<td>PBIBDF-TT</td>
<td>rt</td>
<td>0.12</td>
<td>0.11 ± 0.011</td>
<td>3.0 × 10⁴</td>
<td>6.3</td>
</tr>
<tr>
<td></td>
<td>(Cytop/SiO₂)</td>
<td>0.18</td>
<td>0.13 ± 0.031</td>
<td>3.6 × 10⁴</td>
<td>23.8</td>
</tr>
<tr>
<td></td>
<td>150</td>
<td>0.65</td>
<td>0.48 ± 0.124</td>
<td>5.5 × 10⁴</td>
<td>43.1</td>
</tr>
<tr>
<td></td>
<td>180</td>
<td>0.45</td>
<td>0.30 ± 0.085</td>
<td>1.1 × 10⁴</td>
<td>30.3</td>
</tr>
<tr>
<td></td>
<td>210</td>
<td>0.10</td>
<td>0.06 ± 0.021</td>
<td>1.9 × 10⁴</td>
<td>21.8</td>
</tr>
<tr>
<td>PBIBDF-TV'T</td>
<td>rt</td>
<td>0.11</td>
<td>0.09 ± 0.018</td>
<td>4.2 × 10⁴</td>
<td>30.9</td>
</tr>
<tr>
<td></td>
<td>(Cytop/SiO₂)</td>
<td>0.18</td>
<td>0.16 ± 0.020</td>
<td>3.1 × 10⁴</td>
<td>41.9</td>
</tr>
<tr>
<td></td>
<td>150</td>
<td>0.25</td>
<td>0.19 ± 0.046</td>
<td>2.2 × 10⁵</td>
<td>41.9</td>
</tr>
<tr>
<td></td>
<td>180</td>
<td>0.55</td>
<td>0.44 ± 0.096</td>
<td>1.4 × 10⁵</td>
<td>41.6</td>
</tr>
<tr>
<td>PBIBDF-TAT</td>
<td>rt</td>
<td>0.03</td>
<td>0.02 ± 0.004</td>
<td>1.2 × 10⁵</td>
<td>25.3</td>
</tr>
<tr>
<td></td>
<td>(Cytop/SiO₂)</td>
<td>0.04</td>
<td>0.03 ± 0.006</td>
<td>3.9 × 10⁴</td>
<td>37.9</td>
</tr>
<tr>
<td></td>
<td>150</td>
<td>0.07</td>
<td>0.05 ± 0.012</td>
<td>1.9 × 10⁵</td>
<td>36.8</td>
</tr>
<tr>
<td></td>
<td>180</td>
<td>0.13</td>
<td>0.08 ± 0.025</td>
<td>4.6 × 10⁵</td>
<td>29.9</td>
</tr>
</tbody>
</table>

The evaluation of OTFTs were carried out under vacuum (3 × 10⁻⁴ mbar). Averages from more than 8–10 devices. Evaluated at V_{DS} = 80 V.

decreasing the effect of the residual solvent on the carrier transport, resulting in high mobility.14 The representative output and transfer characteristics of the OTFTs based on the polymers are shown in Fig. 4 and the calculated field-effect performances are listed in Table 2. The optimal annealing temperatures were 150 °C for PBIBDF-TT and 180 °C for PBIBDF-TV'T and PBIBDF-TAT. For the PBIBDF-TT system, the highest electron mobility of 0.65 cm² V⁻¹ s⁻¹ with an I_{on}/I_{off} of 5.5 × 10⁴ was obtained after 150 °C annealing. At a higher annealing temperature of 180 °C, the mobilities dropped slightly to 0.45 cm² V⁻¹ s⁻¹. With further increasing the annealing temperature to 210 °C, the mobilities dropped dramatically to 0.10 cm² V⁻¹ s⁻¹. The worse mobility at 210 °C annealing might be attributed to the thermal-decomposition of large side-chains as evidenced by the TGA curve. For PBIBDF-TV'T, the as-cast thin films exhibited a moderate mobility of 0.18 cm² V⁻¹ s⁻¹. With thermal annealing, the mobility of PBIBDF-TV'T thin films increased, and the highest mobility was 0.55 cm² V⁻¹ s⁻¹ after thermal annealing at 180 °C. The PBIBDF-TAT-based devices displayed the lowest mobility among the three polymers with the highest mobility of 0.13 cm² V⁻¹ s⁻¹ after thermal annealing at 180 °C. No hole transport was observed for the three polymers under vacuum (3 × 10⁻⁴ mbar). This is presumably due to the large hole injection barrier between their low-lying HOMO levels and the work function of gold (~4.7–5.1 eV) under vacuum (3 × 10⁻⁴ mbar) conditions. Another BIBDF-based polymer (PBIBDF-BT), which was reported in our previous paper, could also exhibit n-channel transport under these vacuum conditions.5a

OTFTs' environmental stability for PBIBDF-TT and PBIBDF-TV'T was also monitored over the course of storage under ambient conditions, and the relevant OTFT performances (electron mobility and I_{on}/I_{off}) are displayed in Fig. 5. After 70 days' air exposure, the highest mobilities of PBIBDF-TT and PBIBDF-TV'T still remained at the values of 0.33 and 0.31 cm² V⁻¹ s⁻¹, respectively. Moreover, the I_{on}/I_{off} of the two polymers remained over 10⁴ in the whole course of storage under ambient conditions. PBIBDF-TT and PBIBDF-TV'T thin-films showed robust storage stability, which was doubtless attributed to the low-lying LUMO and HOMO energy levels created by the strong electron-deficient BIBDF unit. The other reason might probably be due to close π–π stacking distance that was also beneficial to defend the diffusion of water and oxygen (see below). However, the mobilities of the three polymers were lower than those of the reported BIBDF-based polymers.5a-c The main reason may be ascribed to the relatively low molecular weight of the three BIBDF-based polymers, which significantly influences the OTFTs’ performances. The polymer semiconductors with high molecular weight usually showed high field-effect performance compared with that of the lower molecular weight ones.15 For BIBDF containing polymers, the reported polymer with the highest mobility so far had an M₉₀ of 77.2 kDa, while the PBIBDF-TT with a mobility of 0.65 cm² V⁻¹ s⁻¹ showed an M₉₀ of only 26.5 kDa. Further optimizations of the molecular weight of PBIBDF-TT and PBIBDF-TV'T for the improvement of the electron mobility are in progress.

2.5. Thin-film microstructure analysis

To elucidate the structure–property relationships in the three BIBDF-based polymers, grazing incident X-ray diffraction (GIXD) and tapping mode atomic force microscopy (AFM) were employed to investigate the crystalline nature, molecular orientation, and morphologies of the three polymer films. The 2D-GIXD images and the corresponding diffractogram profiles of the films with and without annealing are shown in Fig. 6.
The crystallographic parameters are listed in Table S2.† For PBIBDF-TT and PBIBDF-TVT thin films, the non-annealing (N/A) films showed out-of-plane reflection peaks (100) and well defined (200), (300), and (400) diffraction peaks along the out-of-plane $q_z$ axis. Compared with the N/A films, the annealing films for PBIBDF-TT and PBIBDF-TVT exhibited more and stronger diffraction peaks (highly ordered (100)–(500)). The presence of highly ordered reflection peaks

Fig. 4 Typical transfer and output characteristics of OTFT devices based on polymer films coated on Cytop-modified SiO$_2$/Si substrates at an optimized annealing temperature of 150 or 180 °C.

Fig. 5 OTFT performances (electron and $I_{on}/I_{off}$) for PBIBDF-TT and PBIBDF-TAT after exposure to air.
of N/A and annealing films suggested that PBIBDF-TT and PBIBDF-TVT had long-range ordered, lamellar crystalline structures. In contrast, the PBIBDF-TAT thin film displayed relatively poor molecular ordering among the three polymers with defined (100), (200), and (300) diffraction peaks after annealing at 180 °C. The lamellar spacings were 28.96 Å for PBIBDF-TT, 29.45 Å for PBIBDF-TVT, and 29.83 Å for PBIBDF-TAT, which were calculated from their (100) peaks at \( q_z = 0.217, 0.213, \) and 0.211 Å\(^{-1}\). The observed interlayer distances were much shorter than the molecular modeled length of alkyl chains, suggesting that the alkyl chains were not fully extended in the films when coated on the substrates even in the presence of thermal annealing. However, the non-fully extended alkyl chains did not hinder the co-planarity of the main chain. Besides out-of-plane peaks, the in-plane XRD spectra of PBIBDF-TT and PBIBDF-TVT also displayed the (010) reflection peaks in the case of films of both N/A and annealing conditions. These results suggested clearly that the films of PBIBDF-TT and PBIBDF-TVT favored edge-on orientation on the substrate, thus facilitating efficient charge carrier hopping transport. In contrast, the N/A film of PBIBDF-TAT did not show any discernible peak in the \( q_{xy} \) plane, while the annealed film revealed a weak peak centered in the \( q_{xy} \) plane. The (010) diffraction peaks were located at \( q_{xy} = 1.82, 1.79, \) and 1.80 Å\(^{-1}\) for PBIBDF-TT, PBIBDF-TVT, and PBIBDF-TAT, respectively, so the \( \pi-\pi \) stacking distances were 3.45 Å for PBIBDF-TT, 3.51 Å for PBIBDF-TVT, and 3.49 Å for PBIBDF-TAT [Fig. S5†]. The calculated \( \pi-\pi \) stacking distances of the three polymers were slightly smaller than those of the reported BIDF-based polymers,\(^{a-c} \) and even much lower than those of the famous high performance DPP-based polymer PDVT-10 (3.66 Å) and PDVT-8 (3.78 Å).\(^{10} \) The remarkable close \( \pi-\pi \) distance between polymer backbones suggested that strong intermolecular interactions exist. Charge transport of the conjugated polymer is highly dependent on the intermolecular overlap integral. However, the annealed PBIBDF-TAT thin film with the close \( \pi-\pi \) stacking distance also showed miserable performance because of the poor crystalline structures among the three polymers. The close \( \pi-\pi \) distance and the long-range ordered, lamellar crystalline structures both contributed to the high charge carrier mobilities for PBIBDF-TT and PBIBDF-TVT.

The AFM height images of the three polymer thin films are also shown in Fig. 7. For PBIBDF-TT and PBIBDF-TVT, the N/A films showed fine, clustered and nano-fibrillar crystals in the whole area. Such crystalline networks were presumably caused by strong intermolecular interactions. As annealed at 150 or 180 °C, the two polymer films both exhibited larger polycrystalline grains than the N/A films, leading to fewer grain boundaries and therefore higher field effect performance. Further increasing the annealing temperature to 210 °C, the degradation of the large alkyl chains gave rise to large circular domains in the film, which was responsible for the decline in device performance [Fig. S6†]. On the other hand, the N/A thin film of PBIBDF-TAT showed isolated grains with large grain boundaries. At an annealing temperature of 180 °C, the film became well interconnected. The annealed PBIBDF-TAT thin film, however, had poor crystalline networks compared with those of the other two polymer films, which was also responsible for the lowest mobilities among the three BIBDF-based polymers.
3. Conclusion

In this work, new BIBDF-based polymers with three different donors were designed and synthesized. These three polymers showed almost the same LUMO energy levels (−4.0 eV) while they had different crystalline structures in thin-films and varied π-π stacking distances observed in the GIXD characterization. OTFTs based on the three polymers with common architectures and their environmental stability were also investigated. The results indicated that thermal annealing had a substantial influence on crystalline nature, morphologies as well as charge transport. PBIBDF-TT with long-range ordered, lamellar crystalline structure and close π-π stacking distance showed an electron mobility of 0.65 cm² V⁻¹ s⁻¹ with a high I_on/I_off value of over 10⁴, which was the highest one in the three polymers. On the other hand, because of the poor crystalline structure, PBIBDF-TAT displayed a miserable electron mobility of 0.13 cm² V⁻¹ s⁻¹ though the polymer thin film also had a similar π-π stacking distance. Overall, these results suggest that (i) BIBDF is a promising building block for constructing high performance electron transport materials; (ii) the donor unit has a significant effect on BIBDF-based polymers and the field-effect performances can be effectively optimized by introducing different donor units; (iii) the conjugated polymer with not only close π-π stacking distance but also long-range ordered lamellar crystalline structure as well as high molecular weight would show satisfactory OTFT performance.

4. Experimental

4.1. Characterization

Nuclear magnetic resonance (NMR) spectra were recorded using a Mercury plus 600 MHz machine. Elemental analysis of the polymer was performed using a Vario EL instrument. Molecular weights of the polymers were determined by gel permeation chromatography (GPC) analyses on a Waters Series 1525 gel using 1,2,4-trichlorobenzene as an eluent with polystyrene as standards. Thermo-gravimetric analyses (TGA) were conducted with a TA Instruments Q5000 at a heating rate of 10 °C min⁻¹ under nitrogen gas flow. Differential scanning calorimetry (DSC) was conducted under nitrogen using a TA Instruments Q2000. The sample (about 5 mg in weight) was first cooled down to −25 °C, then heated up to 250 °C and held for 2 min to remove thermal history, followed by cooling at a rate of 10 °C min⁻¹ to −25 °C and then heating at a rate of 10 °C min⁻¹ to 250 °C in all cases. UV-vis-NIR absorption spectra were recorded on polymer solutions in chloroform and polymer films cast onto quartz glass using a Perkin-Elmer model λ 20 UV-vis-NIR spectrophotometer. CV measurements were conducted on a CHI 660D electrochemical analyzer under nitrogen in a solution containing tetra-n-butylammonium hexafluorophosphate (0.1 M) in deoxygenated anhydrous acetonitrile at a scan rate of 100 mV s⁻¹. The platinum electrode was used as both the working electrode and the auxiliary electrode, and an Ag/Ag⁺ electrode was used as a reference electrode. Polymer thin films were coated on the surface of the platinum electrode and ferrocene was chosen as a reference.
Grazing-incidence X-ray diffraction (GIXD) studies were performed using 3C beamlines at the Pohang Accelerator Laboratory (PAL) in Korea. The atomic force microscope (AFM) measurements were performed on polymer thin films on a Cytop-modified SiO2/Si substrate using an SPA300HV instrument with an SPI3800 controller (Seiko Instruments).

4.2. Fabrication and characterization of field-effect transistors

Bottom-gate/top-contact OTFT devices were fabricated on a common gate of highly n-doped silicon with a 300 nm thick thermally grown SiO2 dielectric layer. A fluoropolymer Cytop was spin-coated onto an SiO2 dielectric layer (~20 nm). A chloroform solution containing a semiconductor polymer (5 mg mL−1) was dropped onto the Cytop (or OTS) thin film and spin-coated. The polymer films were subsequently annealed at 150, 180 and 210 °C for 30 min under a nitrogen atmosphere. Then Au source–drain electrodes were evaporated on top of the semiconductor layers (56 nm). The OTFT devices had a channel length (L) of 100 µm and a channel width (W) of 800 µm. The evaluation of the OTFTs was performed in a vacuum of Cytop/SiO2 gate-dielectric, and an ambient atmosphere.

4.3. Materials

6-Bromoindoline-2,3-dione was purchased from Sigma-Aldrich Chemical Company, Alfa Aesar Chemical Company and Sinopharm Chemical Reagent Co. Ltd, Shanghai, China. Other chemicals used in this work were purchased from Sigma-Aldrich Chemical Company, Alfa Aesar Chemical Company and Sinopharm Chemical Reagent Co. Ltd, China. All commercially available reagents were used without further purification. Tetrahydrofuran (THF) and toluene were freshly distilled over sodium wire under nitrogen prior to use. 2,5-Bis(trimethylstannyl)thieno[3,2-b]thiophene (M1), 1,2-bis(5-(trimethylstannyl)-thiophene-2-yl)ethane (M2) and 1,2-bis(5-(trimethylstannyl)-thiophene-2-yl)ethyne (M3) were synthesized via published procedures.3–16

4.4. Synthesis of monomers and polymers

Synthesis of compound 1. To a solution of 2,5-dihydroxy-1,4-benzenedicarboxylic acid (5.6 g, 24.79 mmol) in toluene (60 mL) under nitrogen atmosphere, acetic anhydride (100 mL) was added. The reaction mixture was refluxed for 4 hours. After removing the solvent, the crude product was washed with hot alcohol. A white precipitate formed, which was used in the next step without any further purification.

Synthesis of compound 2. Anhydrous potassium carbonate (636 g, 45.99 mmol) and 6-bromoindole-2,3-dione (2.65 g, 11.73 mmol) were dissolved in anhydrous N,N-dimethylformamide (DMF, 50 mL) at 70 °C under a nitrogen atmosphere, after vigorous stirring for 1 h. 4-Bromo-alkyl (9.04 g, 14.08 mmol) was added dropwise and the mixture was kept under stirring and heated overnight at 70 °C. After cooling to room temperature, the solution was poured into water (300 mL) and then extracted with dichloromethane. The organic layer was collected and dried with anhydrous sodium sulfate. Solvent was removed under reduced pressure and the residue was purified by flash chromatography on silica gel with petroleum–dichloromethane–diethyl ether (15:1:1) as an eluent to give the title compound (6.52 g, 55.8%). The compound was used in the next step without any further purification.

Synthesis of BIBDF. Compound 1 (0.77 g, 4.06 mmol), compound 2 (6.40 g, 8.13 mmol), and toluenesulfonic acid (TsOH, 0.22 g, 1.14 mmol) were stirred in acetic acid (40 mL) under a nitrogen atmosphere. The mixture was refluxed for 17 h under nitrogen. The reaction mixture was then cooled to room temperature and filtered. The solid was washed with methanol. The crude product was further purified by column chromatography on silica gel using dichloromethane–petroleum ether (1:1) as an eluent to obtain the title compound (3.23 g, 45.0%).

1H NMR (600 MHz, CDCl3, ppm): δ = 9.08 (s, 2H), 8.90 (d, 2H), 7.17 (d, 2H), 6.91 (s, 2H), 3.71 (d, 4H), 1.68 (s, 4H), 1.20–1.35 (m, 142H), 0.86 (t, 12H).

Synthesis of PBIBDF-TT and PBIBDF-TAT. The same procedure was used as those for PBIBDF-TT. The compounds used were PD12[db]3 (0.0042 g, 0.0046 mmol), P(tol-tol)2, 0.012 g, 0.038 mmol) and degassed toluene (8 mL) were added to a Schlenk tube. The solution was subjected to three cycles of evacuation and admission of nitrogen. The mixture was stirred at 110 °C for 48 h. After cooling down to room temperature, the mixture was poured into methanol (100 mL) and stirred for 2 h. A black precipitate was collected by filtration. The product was purified through Soxhlet extraction using methanol and dichloromethane to remove oligomers and other impurities. The remaining polymer was extracted with hot chloroform in an extractor for 24 h. After removing the solvent, a black solid was collected (0.22 g, 71.7%). Elemental analysis: calculated for (C12H17N2O2S2)n (%): C, 78.80, H, 10.18, N, 1.64, found (%): C, 78.68, H, 9.88, N, 1.49. GPC: Mn = 26.5 kDa, PDI = 1.65.

Synthesis of PBIBDF-TVT and PBIBDF-TAT. The same procedures were used as those for PBIBDF-TT. The compounds used were PD12[db]3 (0.0042 g, 0.0046 mmol), P(tol-tol)2, 0.012 g, 0.038 mmol), BIBDF (0.24 g, 0.14 mmol), P(tol-tol)2, 0.012 g, 0.038 mmol) and degassed toluene (8 mL) were added to a Schlenk tube. The solution was subjected to three cycles of evacuation and admission of nitrogen. The mixture was stirred at 110 °C for 48 h. After cooling down to room temperature, the mixture was poured into methanol (100 mL) and stirred for 2 h. A black precipitate was collected by filtration. The product was purified through Soxhlet extraction using methanol and dichloromethane to remove oligomers and other impurities. The remaining polymer was extracted with hot chloroform in an extractor for 24 h. After removing the solvent, a black solid was collected (0.22 g, 71.7%). Elemental analysis: calculated for (C12H17N2O2S2)n (%): C, 78.80, H, 10.18, N, 1.64, found (%): C, 78.68, H, 9.88, N, 1.49. GPC: Mn = 26.5 kDa, PDI = 1.65.

4.5. Synthesis of polymers

4.6. Characterization of polymers

4.7. Characterization of field-effect transistors

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